

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 79 A

Features

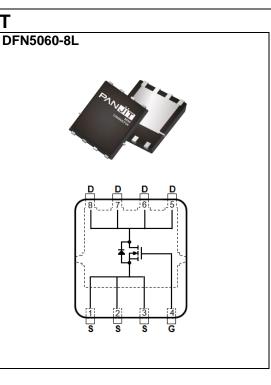
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A < 5.9m\Omega$

40 V

- Rds(on), Vgs@7V, Id@20A<7.3m Ω
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	
Drain-Source Voltage		V _{DS}	40	
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current ^(Note 3)	T _C =25°C		79	
	Tc=100°C	I _D	55	А
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	316	
Power Dissipation	T _C =25°C		65	
	Tc=100°C	PD	33	W
Continuous Drain Current ^(Note 4)	T _A =25°C		17.7	
	T _A =70°C	ID	14.8	— A
Power Dissipation	T _A =25°C	De	3.3	14/
	T _A =70°C	PD	2.3	W
Single Pulse Avalanche Energy ^(Note 5)		Eas	100	mJ
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	2.3	°C/W
	Junction to Ambient	R _{θJA}	45	C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static				1			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	2	2.8	3.5		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	4.7	5.9	mΩ	
		V _{GS} =7V, I _D =20A	-	5.6	7.3		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)	-	-	•		•	-	
Total Gate Charge	Qg	V _{DS} =32V, I _D =20A,	-	23	-		
Gate-Source Charge	Qgs		-	5	-	nC	
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	6	-		
Input Capacitance	Ciss		-	1283	-	pF	
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	252	-		
Reverse Transfer Capacitance	Crss	f=1MHz	-	46	-		
Gate resistance	Rg	f=1MHz	-	0.8	-	Ω	
Turn-On Delay Time	td _(on)		-	14	-		
Turn-On Rise Time	tr	V _{DS} =32V, I _D =20A,	-	3	-		
Turn-Off Delay Time	td _(off)	V _{GS} =10V, R _G =3Ω	-	24	-	ns	
Turn-Off Fall Time	tf		-	5	-		
Drain-Source Diode	·						
Diode Forward Current	Is	T 05°0	-	-	79		
Pulsed Diode Forward Current	I _{SM}	T _C =25 [°] C	-	-	316	A	
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.85	1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =20A	-	24	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	11	-	nC	

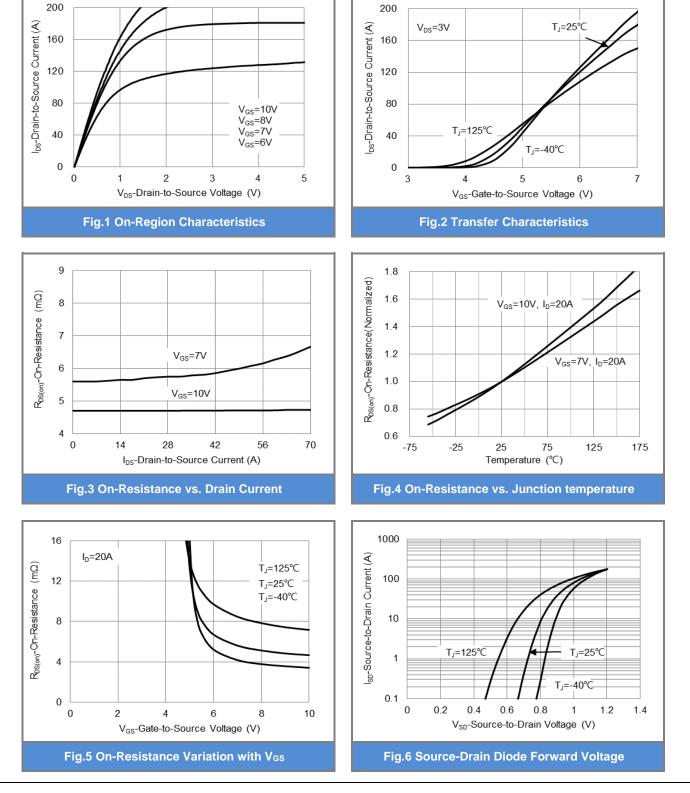
NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=2.3^{\circ}C/W$.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=20A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.

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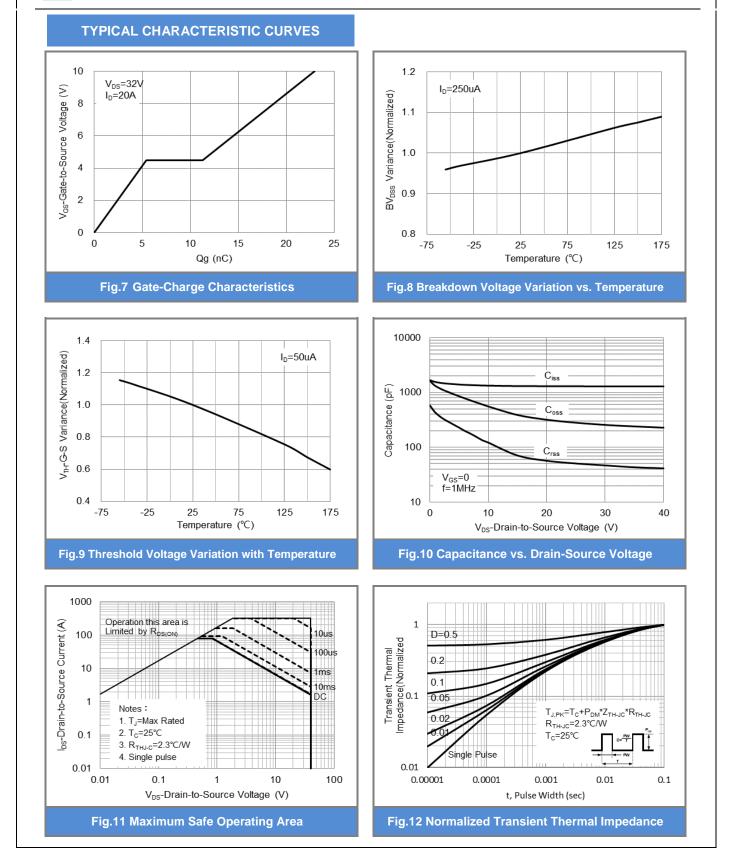


PJQ5546V-AU

TYPICAL CHARACTERISTIC CURVES

April 18,2023

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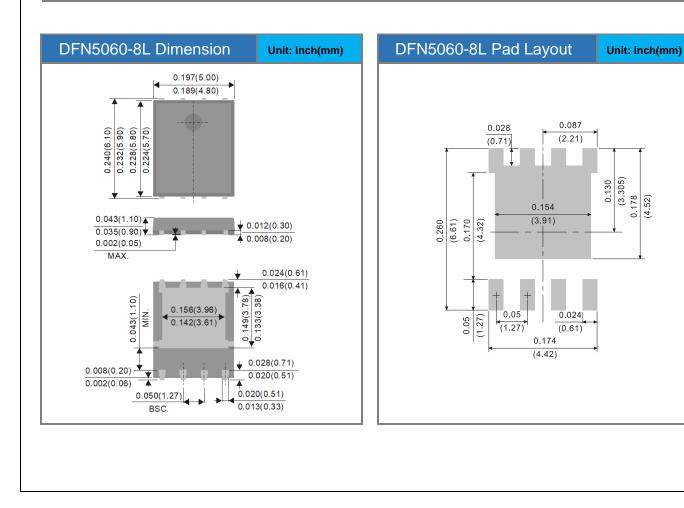
PJQ5546V-AU



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJQ5546V-AU	DFN5060-8L	3K pcs / 13" reel	Q5546V	

Packaging Information & Mounting Pad Layout





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